

Data sheet acquired from Harris Semiconductor SCHS115D – Revised September 2003

# CD4093B Types

# CMOS Quad 2-Input NAND Schmitt Triggers

High-Voltage Types (20 Volt Rating)

■ CD4093B consists of four Schmitttrigger circuits. Each circuit functions as a two-input NAND gate with Schmitt-trigger action on both inputs. The gate switches at different points for positive- and negativegoing signals. The difference between the positive voltage (V<sub>N</sub>) and the negative voltage (V<sub>N</sub>) is defined as hysteresis voltage (V<sub>H</sub>) (see Fig. 2).

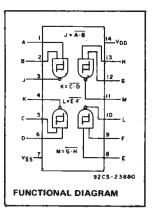
The CD4093B types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Features:

- Schmitt-trigger action on each input with no external components
- Hysteresis voltage typically 0.9 V at
   V<sub>DD</sub> = 5 V and 2.3 V at V<sub>DD</sub> = 10 V
- Noise immunity greater than 50%
- No limit on input rise and fall times
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range, 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

#### Applications:

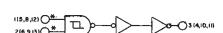
- Wave and pulse shapers
- High-noise-environment systems
- Monostable multivibrators
- Astable multivibrators
- NAND legic



#### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges.

CHARACTERISTIC	MIN.	MAX.	UNITS
Supply Voltage Range			
(T <sub>A</sub> = Full Package			
Temp. Range)	3	18	٧



\*ALL INPUTS PROTECTED BY CMOS PROTECTION NETWORK

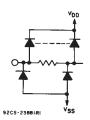


Fig. 1 - Logic diagram-1 of 4 Schmitt triggers.

#### MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS	-0.5V to V <sub>DD</sub> +0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
PACKAGE THERMAL IMPEDANCE, θ <sub>JA</sub> (See Note 1):	
E package	80°C/W
M package	86°C/W
NS package	76°C/W
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	100mW
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (T <sub>sto</sub> )	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 $\pm$ 1/32 inch (1.59 $\pm$ 0.79mm) from case for 10s max	+265°C

NOTE 1: Package thermal impedance is calculated in accordance with JESD 51-7.

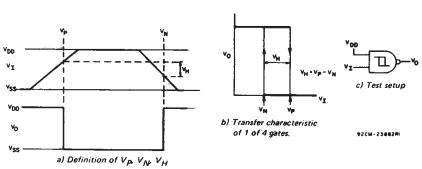


Fig. 2 - Hysteresis definition, characteristic, and test setup.

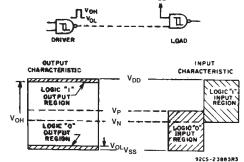


Fig. 3 - Input and output characteristics.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

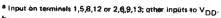


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## CD4093B Types

STATIC	ELECTRICAL	CHARACTERISTICS

CHARACTER- ISTIC		DITIC			MITS A	T INDIC	ATED T	EMPER/	ATURES	(°C)	UNITS
	Vo	VIN	VDD	100					+25		1
	(V)	(V)	(V)	-55	-40	+85	+125	MIN.	TYP.	MAX.	1
Quiescent Device	_	0,5	5	1	1	30	- 30		0.02	1	
Current, IDD		0,10	10	2	2	60	60		0.02	2	μΑ
Max:	_	0,15	15	4	- 4	120	120 -	-	0.02	-4	1 "
		0,20	20	20	20	600	600	-	.0.04	20	1
Positive Trigger	_	а	5	2.2	2.2	2.2	2.2	2.2	2.9		
Threshold Voltage	_	a	10	4.6	4.6	4.6	4.6	4.6	5.9		
Vρ Min.	-	a	15	6.8	6.8	6.8	6.8	6.8	8.8		
	-	b	5	2.6	2.6	2.6	2.6	2.6	3.3	-	٧
	_	b	10	5.6	5.6	5.6	5.6	_ 5.6	7.		1
	-	b	15	6.3	6.3	6.3	6.3	6.3	9.4	-	1
Vp Max.	·	а	5	3.6	3.6	3.6	3.6	-	2.9	3.6	
	<u> </u>	a	10	7.1	7.1	7.1	.7.1		5.9	7.1	1
		а	15	10.8	10.8	10.8	10.8		8.8	10.8	l v
	-	b	5	4	4	4	. 4	-	3.3	4	1
	_	b	10	8.2	8.2	8.2	8.2	_	7	8.2	1
		b	15	12.7	12.7	12.7	12.7	-	9.4	12.7	1
Negative Trigger	_	а	5	0.9	0.9	0.9	0.9	0.9	1.9	-	
Threshold Voltage V <sub>N</sub> Min.	.j-,	a	10	2.5	2.5	2.5	2.5	2.5	3.9	_	
		а	15	4	4	4	4	4	5.8		v
	-	b	5	1.4	1.4	1.4	1.4	1.4	2.3		. *
	_	b	10	3.4	3.4	3.4	3.4	3.4	5.1	- 1	
-	- 1	b	15	4.8	4.8	4.8	4.8	4.8	7.3		
V <sub>N</sub> Max.	- 1	а	5	2.8	2.8	2.8	2.8	12	1.9	2.8	
	-	- a	10	5.2	5.2	5.2	5.2	_	3.9	5.2	
1	-	а	15	7.4	7.4	7.4	7.4		5.8	7.4	v
İ	-	ь	5	3.2	3.2	3.2	3.2	-	2.3	3.2	V
	-	b	10.	6.6	6.6	6.6	6.6		5.1	6.6	
j	-	b	15	9.6	9.6	9.6	9.6		7.3	9.6	
Hysteresis Voltage	-	а	5	0.3	0.3	0.3	0.3	0.3	0.9	_	
V <sub>H</sub> Min.	-	а	10	1.2	1.2	1.2	1.2	1.2	2.3	_	
ļ	-	а	15	1.6	1.6	1.6	1.6	1.6	3.5	_	V
ļ		, Ь,	5	0.3	0.3	0.3	0.3	0.3	0.9		٧
Ţ.	-	Ь	10	1.2	1.2	1.2	1.2	1.2	2.3		
f	-	b	15	1.6	1.6	1.6	1.6	1.6	3.5	_	
V <sub>H</sub> Max.	-	а	5	1.6	1.6	1.6	1.6	-	0.9	1.6	
.,,	- 1	а	10	3.4	3.4	3.4	3.4	-	2.3	3.4	
	-	а	15	5	5	5	5		3.5	5	17
ļ		ь	5	1.6	1.6	1.6	1.6		0.9	1.6	V
ŀ	_	ь	10	3.4	3.4	3.4 .	3.4	_ 1	2.3	3.4	
	_	ь	15	5	5	5	- 5	- 7.	3,5	5	



b Input on terminals 1 and 2, 5 and 6,8 and 9, or 12 and 13; other inputs to VDD-

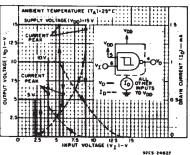


Fig. 4 - Typical current and voltage transfer characteristics.

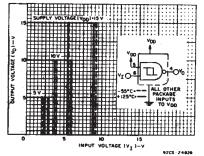


Fig. 5 — Typical voltage transfer characteristics as a function of temperature.

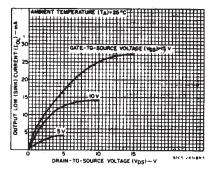


Fig. 6 — Typical output low (sink) current characteristics.

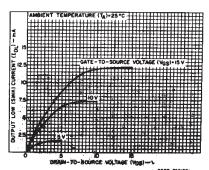


Fig 7 - Minimum output low (sink) current characteristics.

## CD4093B Types

#### STATIC ELECTRICAL CHARACTERISTICS (CONT'D)

CHARACTER- ISTIC	COI	NDITI	ONS	LIM	LIMITS AT INDICATED TEMPERATURES (°C)							
	V <sub>O</sub>	VIN.	VDD			Τ	T		+25			
	(V)	(V)	,(V)	-55	40	+85	+125	MIN.	TYP.	MAX.	1	
Output Low (Sink)	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	_		
Current,	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	. –	1	
I <sub>OL</sub> Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_	mA	
Output High (Source) Current,	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	""	
	2.5	0,5	5	, -2	-1.8	-1.3	-1.15	-1.6	-3.2	-	ı	
	9.5	0,10	10	- 1.6	-1.5	-1,1	-0.9	-1.3	-2.6	_		
I <sub>OH</sub> Min.	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	6.8	. –		
Output Voltage	-	0,5	5		: (	0.05			0	0.05		
Low Level,	1	0,10	10	,	(	0.05			0	0.05		
VOL Max.	i	0,15	15			0.05		· -	0	0.05	v	
Output Voltage	1	0,5	5		- 4	1.95		4.95	5	-		
High-Level, VOH Min.	. 1	0,10	10		9	9.95		9.95	10	-		
	-	0,15	15		14	1.95		14.95		_		
Input Current, I <sub>IN</sub> Max.	1	0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μА	

#### **DYNAMIC ELECTRICAL CHARACTERISTICS**

At  $T_A = 25^{\circ}C$ ; Input  $t_r$ ,  $t_f = 20$  ns,  $C_L = 50$  pF,  $R_L = 200 k\Omega$ 

CHARACTERISTIC	TEST CONDI	TEST CONDITIONS			UNITS
		V <sub>DD</sub> VOLTS	TYP.	MAX.	UNITS
Propagation Delay Time:		5	190	380	1
tPHL,		10	90	180	ns
tPLH telephone		15	65	130	
-		5	100	200	1
Transition Time, tTHL,		10	50	100	ns
<sup>t</sup> TLH	*	15	40	80	-
Input Capacitance, CIN	Any Input		5	7.5	pF.

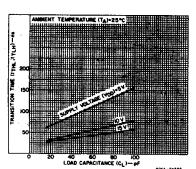


Fig. 11 – Typical transition time vs. load capacitance.

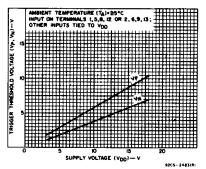


Fig. 12 — Typical trigger threshold voltage vs.  $V_{DD}$ 

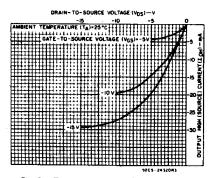


Fig. 8 – Typical output high (source) current characteristics.

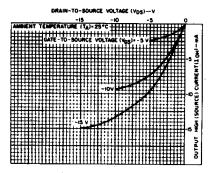


Fig. 9 — Minimum output high (source) current characteristics.

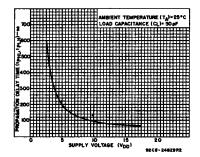


Fig. 10 — Typical propagation delay time vs. supply voltage.

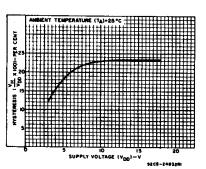


Fig. 13 – Typical per cent hysteresis vs. supply voltage.

## CD4093B Types

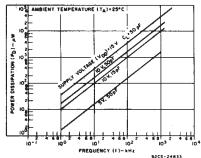


Fig. 14 - Typical power dissipation vs. frequency characteristics.

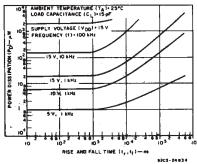


Fig. 15 - Typical power dissipation vs. rise and fall times.

TO CONTROL SIGNAL OR VDD

1/4 CD4093B

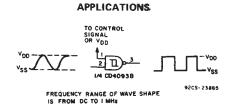
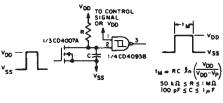


Fig. 16 - Wave shaper.



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Fig. 18 - Astable multivibrator.

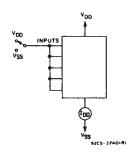


Fig. 19 - Quiescent device current test circuit.

Fig. 17 - Monostable multivibrator.

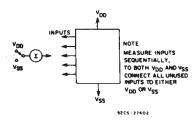
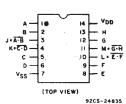


Fig. 20 - Input current test circuit.



TERMINAL ASSIGNMENT

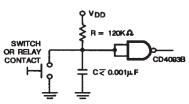


Fig. 21 - Contact Debaucer

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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
7704602CA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	7704602CA CD4093BF3A	Samples
CD4093BE	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4093BE	Samples
CD4093BEE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4093BE	Samples
CD4093BF	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4093BF	Samples
CD4093BF3A	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	7704602CA CD4093BF3A	Samples
CD4093BM	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093BM	Samples
CD4093BM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093BM	Samples
CD4093BM96E4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093BM	Samples
CD4093BM96G4	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093BM	Samples
CD4093BMG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093BM	Samples
CD4093BMT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	CD4093BM	
CD4093BNSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093B	Samples
CD4093BNSRG4	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4093B	Samples
CD4093BPW	OBSOLETE	TSSOP	PW	14		TBD	Call TI	Call TI	-55 to 125	CM093B	
CD4093BPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM093B	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

## PACKAGE OPTION ADDENDUM

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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD4093B, CD4093B-MIL:

Catalog: CD4093B

Automotive: CD4093B-Q1, CD4093B-Q1

Military: CD4093B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects

## **PACKAGE OPTION ADDENDUM**

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• Military - QML certified for Military and Defense Applications

**PACKAGE MATERIALS INFORMATION** 

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4093BM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4093BNSR	so	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4093BPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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## \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4093BM96	SOIC	D	14	2500	356.0	356.0	35.0
CD4093BNSR	SO	NS	14	2000	356.0	356.0	35.0
CD4093BPWR	TSSOP	PW	14	2000	356.0	356.0	35.0

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4093BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4093BE	N	PDIP	14	25	506	13.97	11230	4.32
CD4093BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4093BEE4	N	PDIP	14	25	506	13.97	11230	4.32
CD4093BM	D	SOIC	14	50	506.6	8	3940	4.32
CD4093BMG4	D	SOIC	14	50	506.6	8	3940	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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